NSN 5961-01-179-5445

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-179-5445 **Inclosure Material:** Glass **Overall Length:** 0.450 inches **Terminal Length:** 0.700 inches **Overall Diameter:** 0.085 inches **Function For Which Designed:** Bidirectional and zener diode **Component Name And Quantity:** 2 semiconductor device diode **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all semiconductor device diode Voltage Rating In Volts Per Characteristic: 15.0 regulator voltage all semiconductor device diode **Voltage Tolerance In Percent:** -10.0/+10.0 all semiconductor device diode **Current Rating Per Characteristic:** 17.00 milliamperes all primaries horsepower metric all semiconductor device diode **Power Rating Per Characteristic:** 3.0 watts small-signal input power, common-collector preset all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Special Features:** All semiconductor device diode junction pattern arrangement: pn **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: